

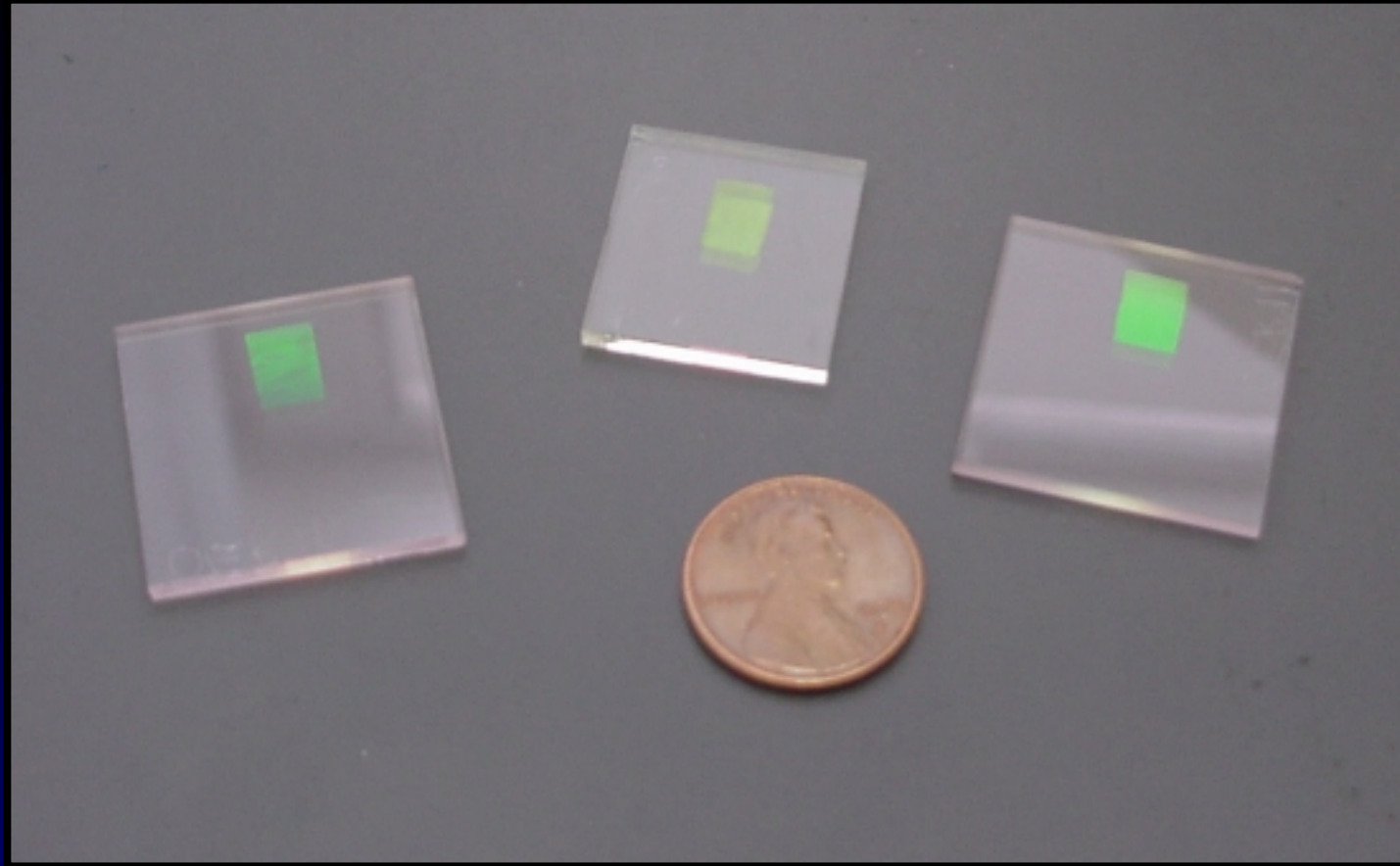
Single-frequency Er/Yb Co-doped Waveguide Lasers

Berton E. Callicoatt, Robert Hickernell, and Norman Sanford

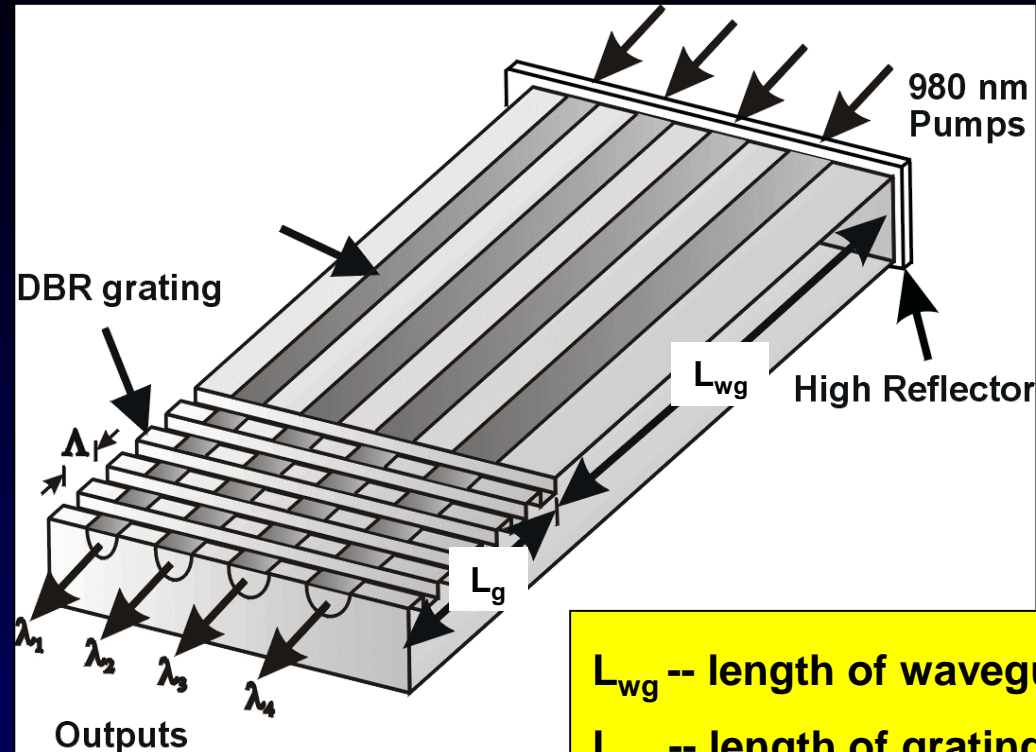


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Single-Frequency DBR Lasers



Single-frequency DBR Laser



L_{wg} -- length of waveguide (15-20 mm)


L_g -- length of grating (6mm)

Why Waveguide Lasers?

High rare-earth-doping concentrations

- High power from compact, monolithic package
- Simple environmental isolation

Long upper-state lifetime of laser transition

- $\sim 10\text{ms}$  longer than semiconductors (ns)
leads to narrower linewidth $< 10\text{ kHz}$

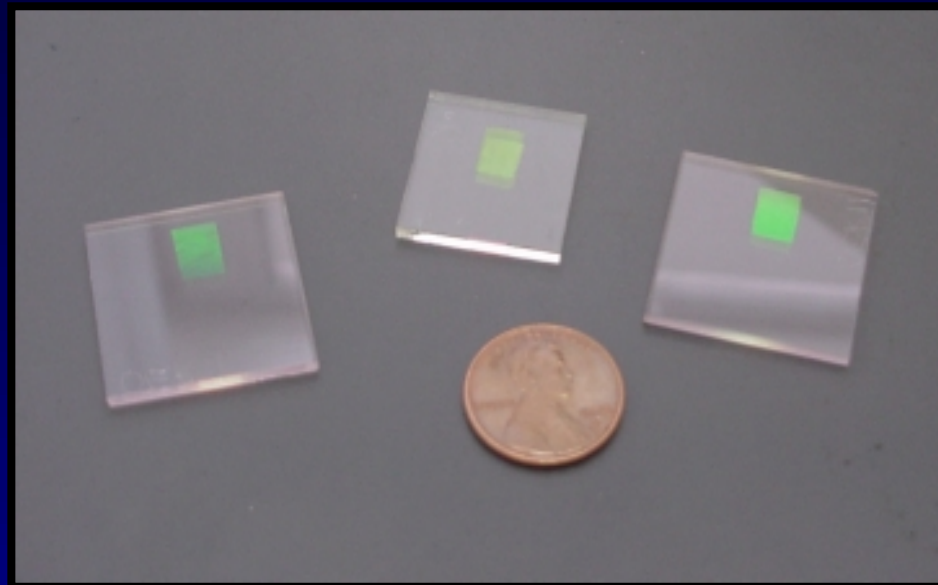
Mechanical & thermal stability

- Reduced microphonic noise  environmental isolation

Easily integrated into fiber-based systems

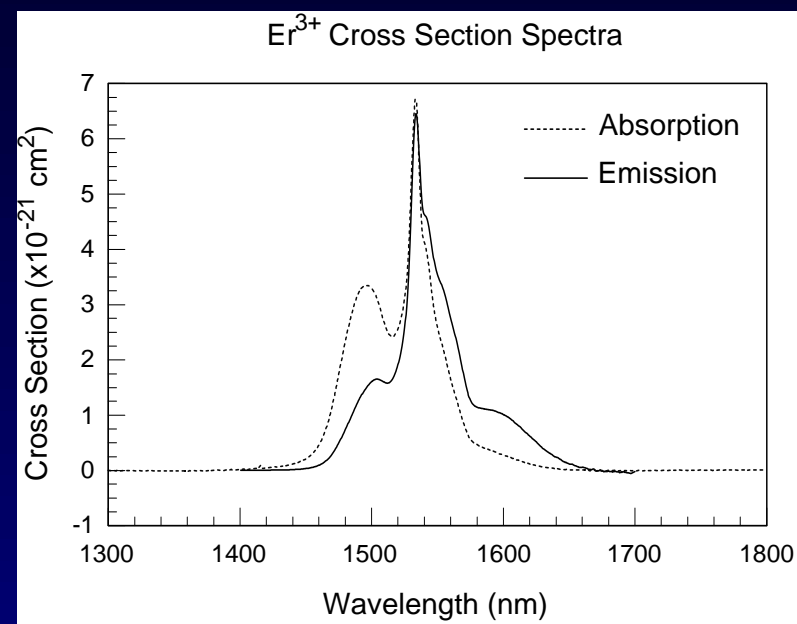
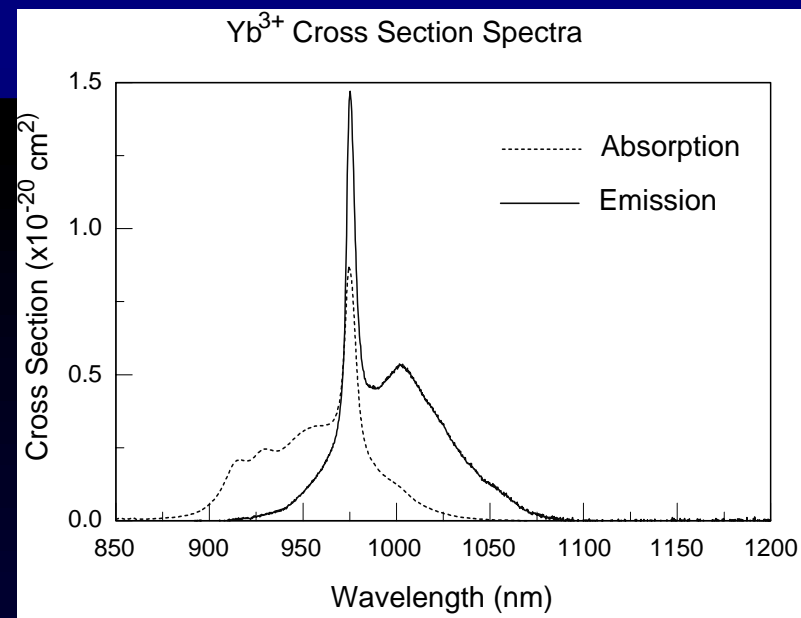
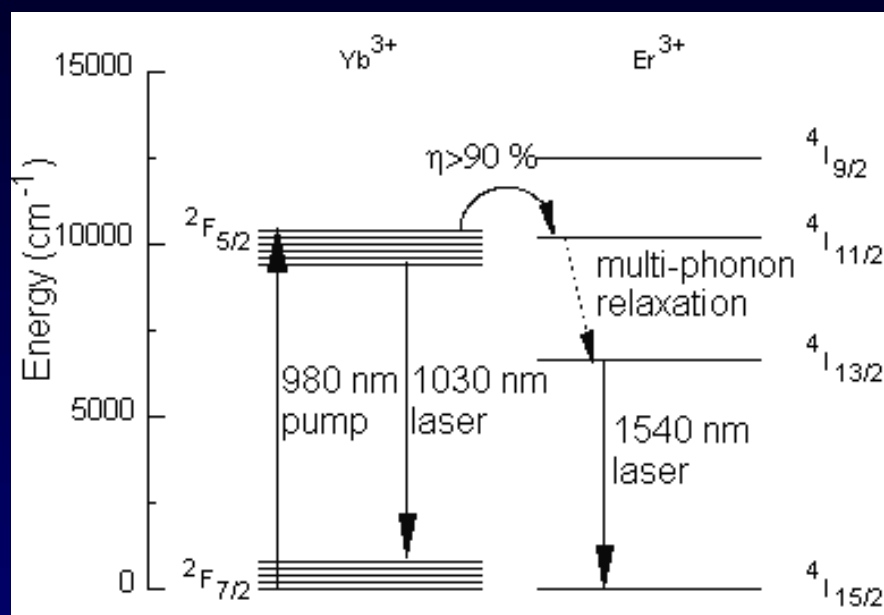
Applications

- All optical microwave and RF signal generation.
- Laser sources for photonic crystal cavities.
- Remote sensing and ranging.
- High-speed detector testing.
- Semiconductor laser characterization.
- Optical frequency synthesis and metrology.
- Telecommunications.



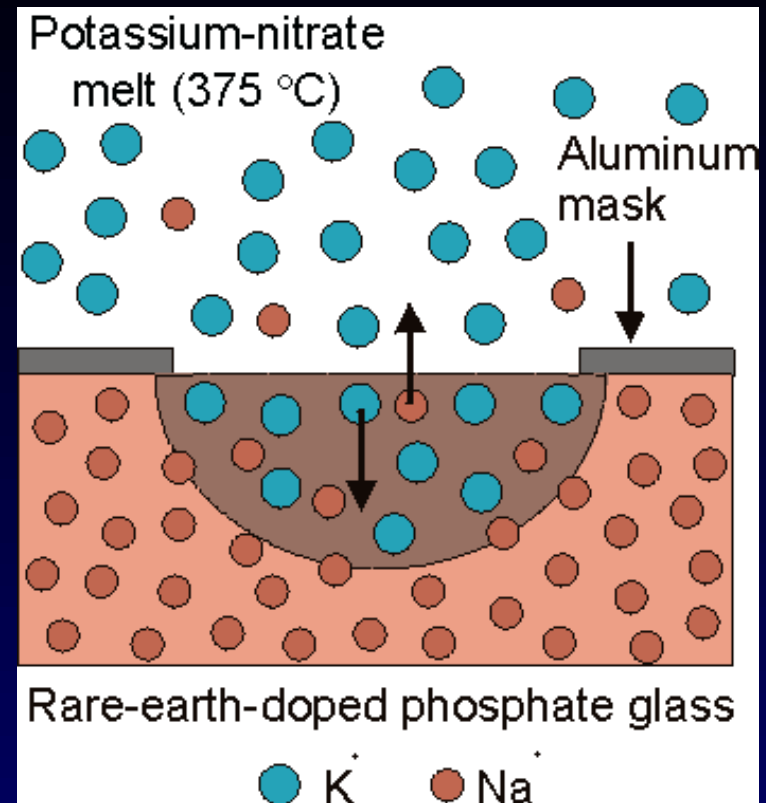
Spectroscopic Properties Of Er^{3+} and Yb^{3+} in Phosphate glass

Typical Dopant Levels:
 $1 \times 10^{20}/\text{cm}^3$ for Er^{3+}
 $4 \times 10^{20}/\text{cm}^3$ for Yb^{3+}



Ion Exchange Process

- **Yb/Er-codoped phosphate glass host**
- **K^+ - Na^+ ion exchange**
 - KNO_3 melt @ 375 °C
 - 4 hours
- **Dice & Polish waveguide end facets**
- **Remove Aluminum Mask**



DBR Fabrication

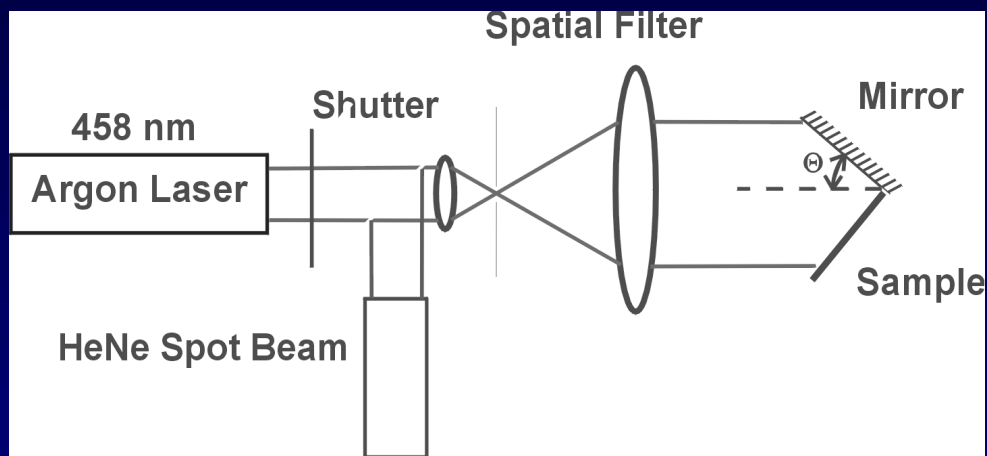
- Holographic exposure of photoresist
 - 0.5 μm thick photoresist
 - 1st order diffraction maximized during developing
- Ar ion sputter etch to transfer grating

Grating Period Defined by:

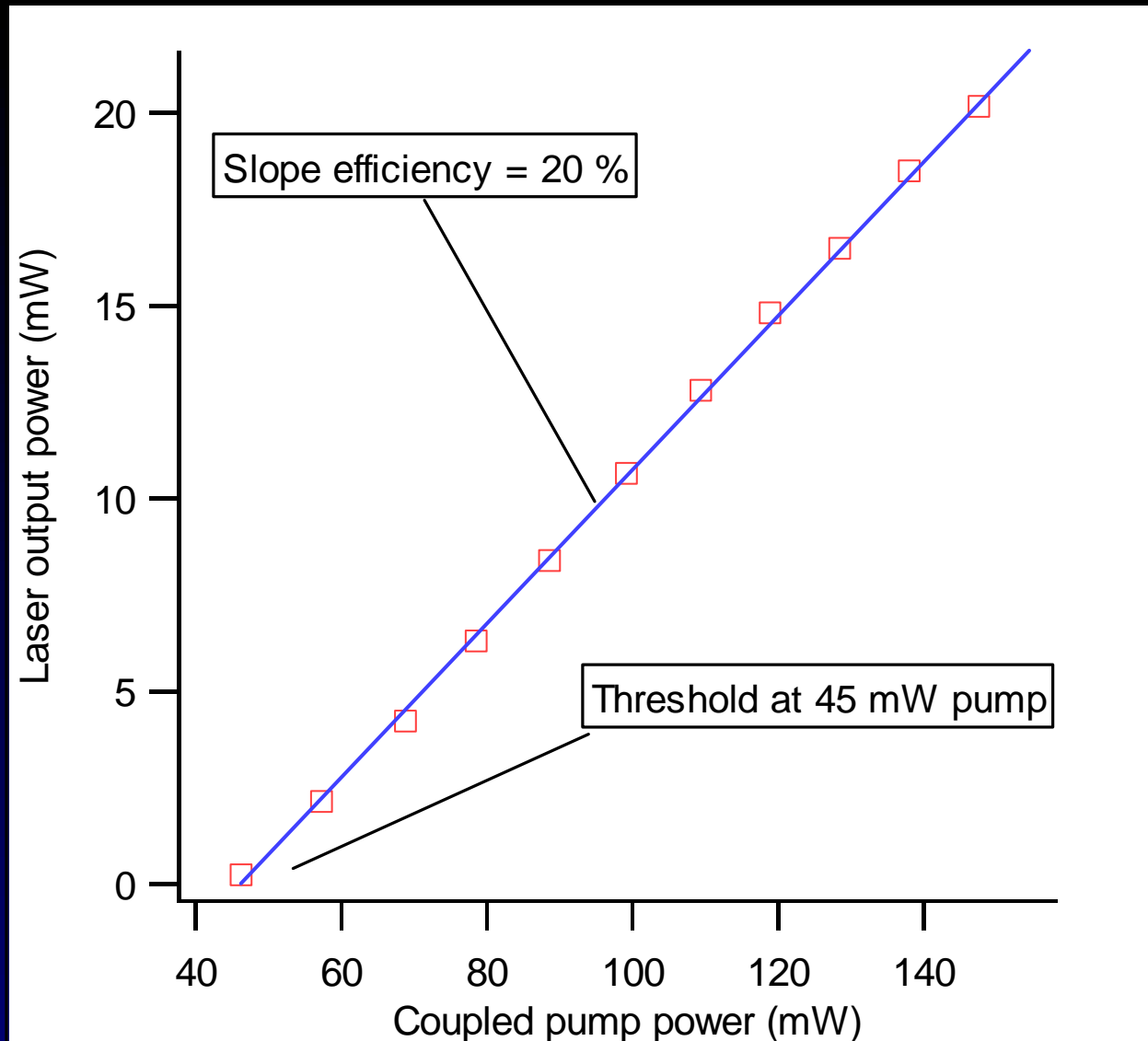
$$\Lambda = \frac{\lambda_0}{2N_{\text{eff}}} = \frac{\lambda_{\text{exp}}}{2n\sin\theta_{\text{exp}}}$$

Exposure Angle

$$\theta_{\text{exp}} = \sin^{-1} \left(\frac{N_{\text{eff}} \lambda_{\text{exp}}}{n_{\text{air}} \lambda_0} \right)$$



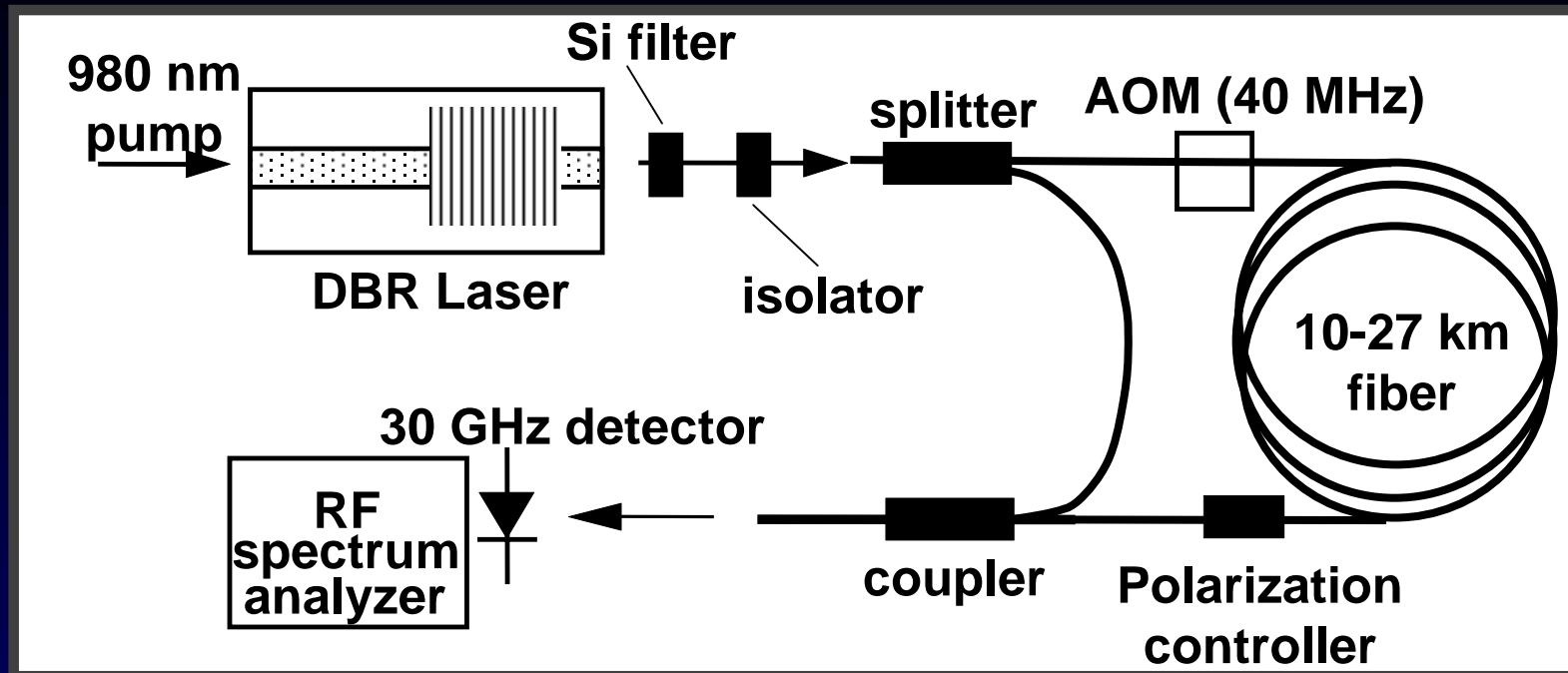
DBR Laser Output Power



Over 80 mW with higher power pump laser

Linewidth Measurement

Delayed Self-heterodyne



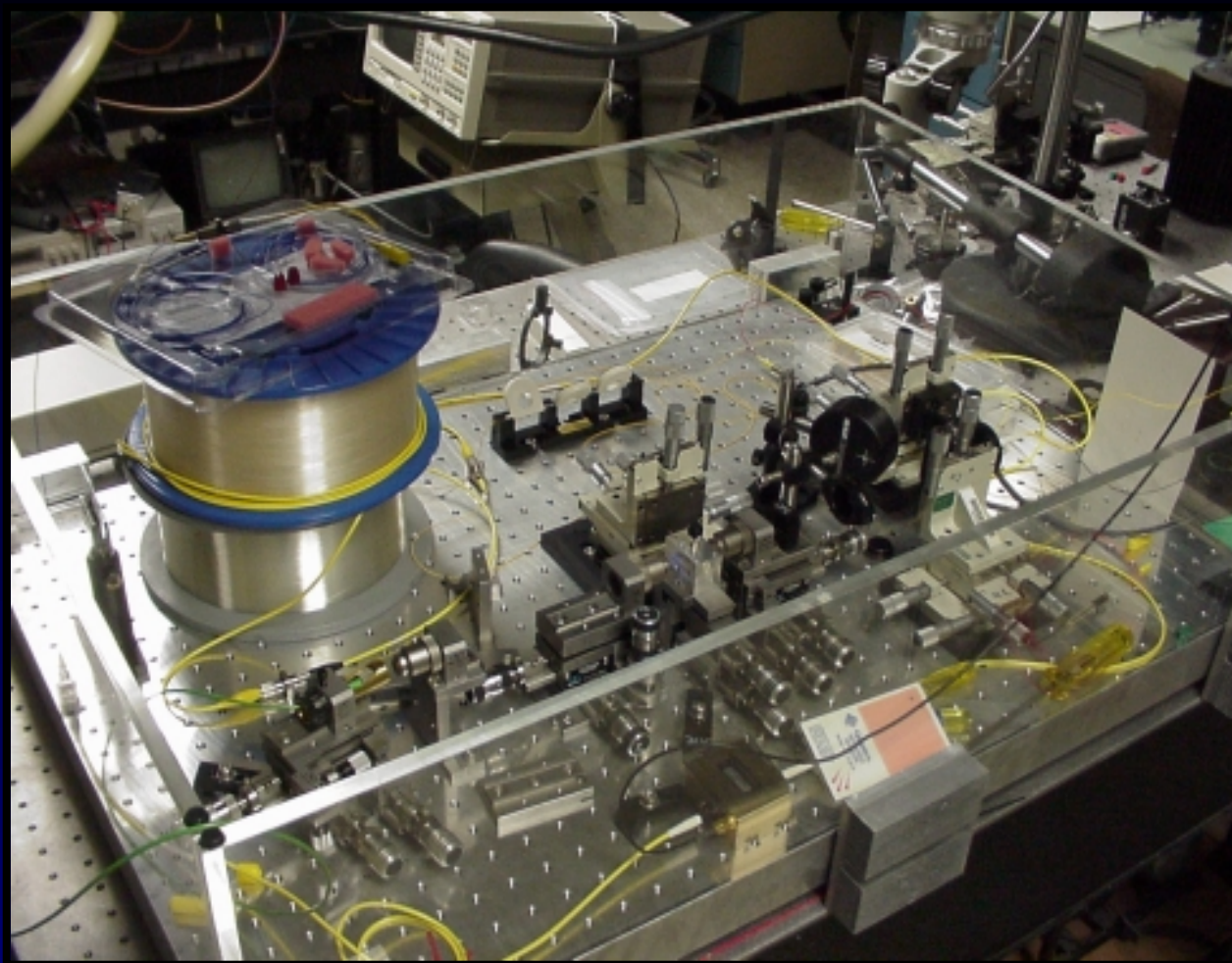
Lorentzian

$$\tau_c = \frac{1}{\pi \cdot \Delta \nu}$$

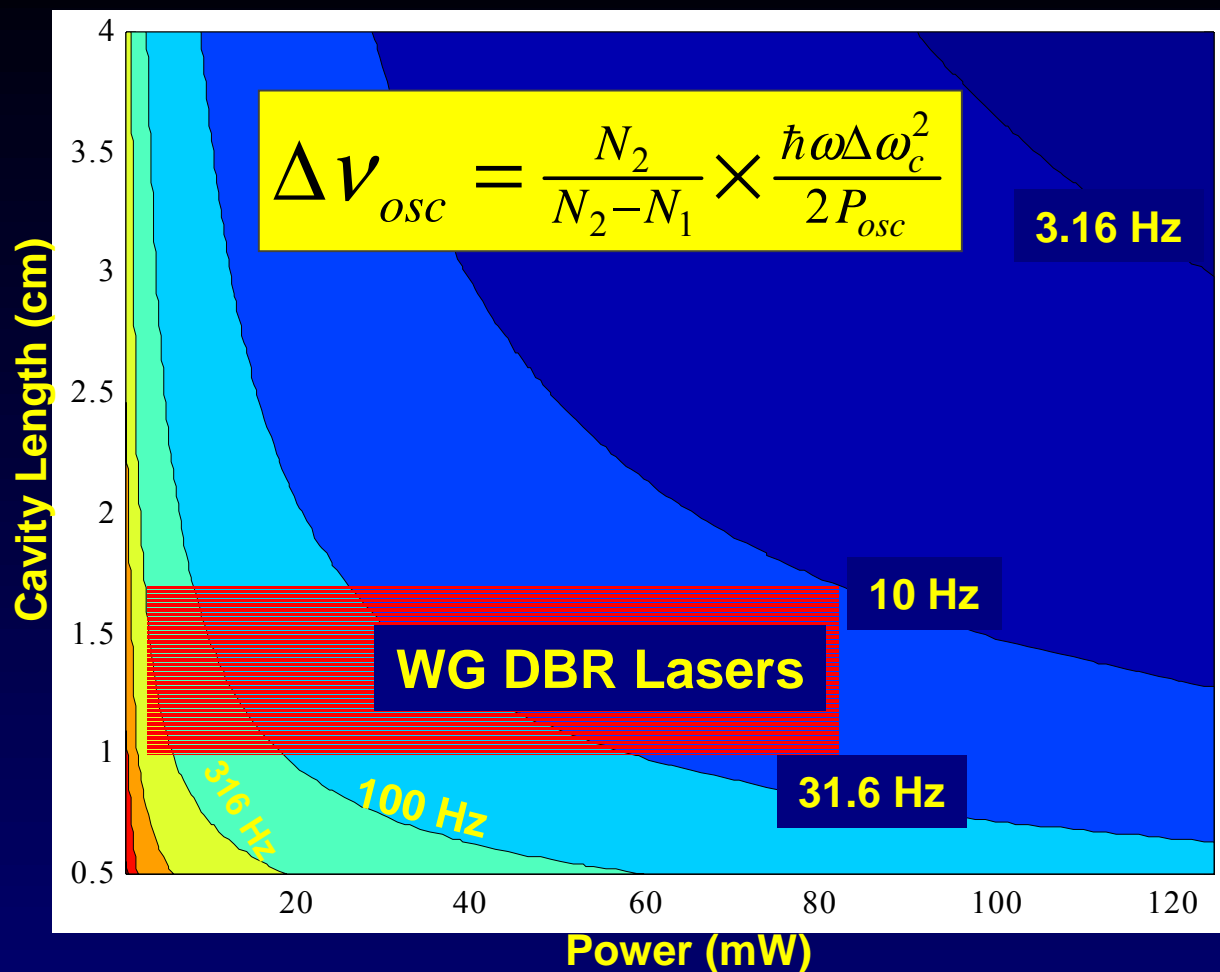
Resolution

$$\Delta \nu = 2.4 \text{ kHz}$$

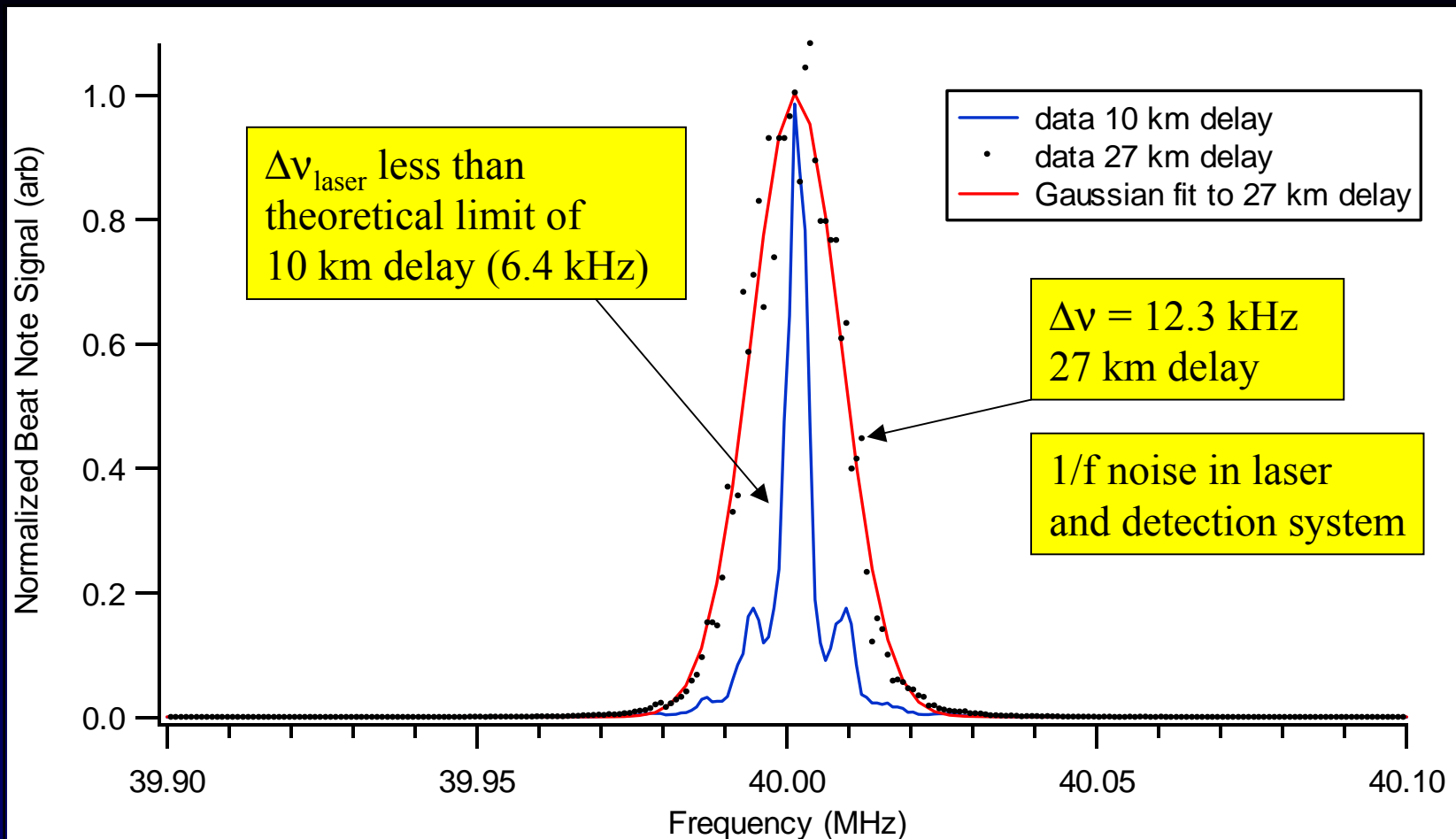
Linewidth Measurement



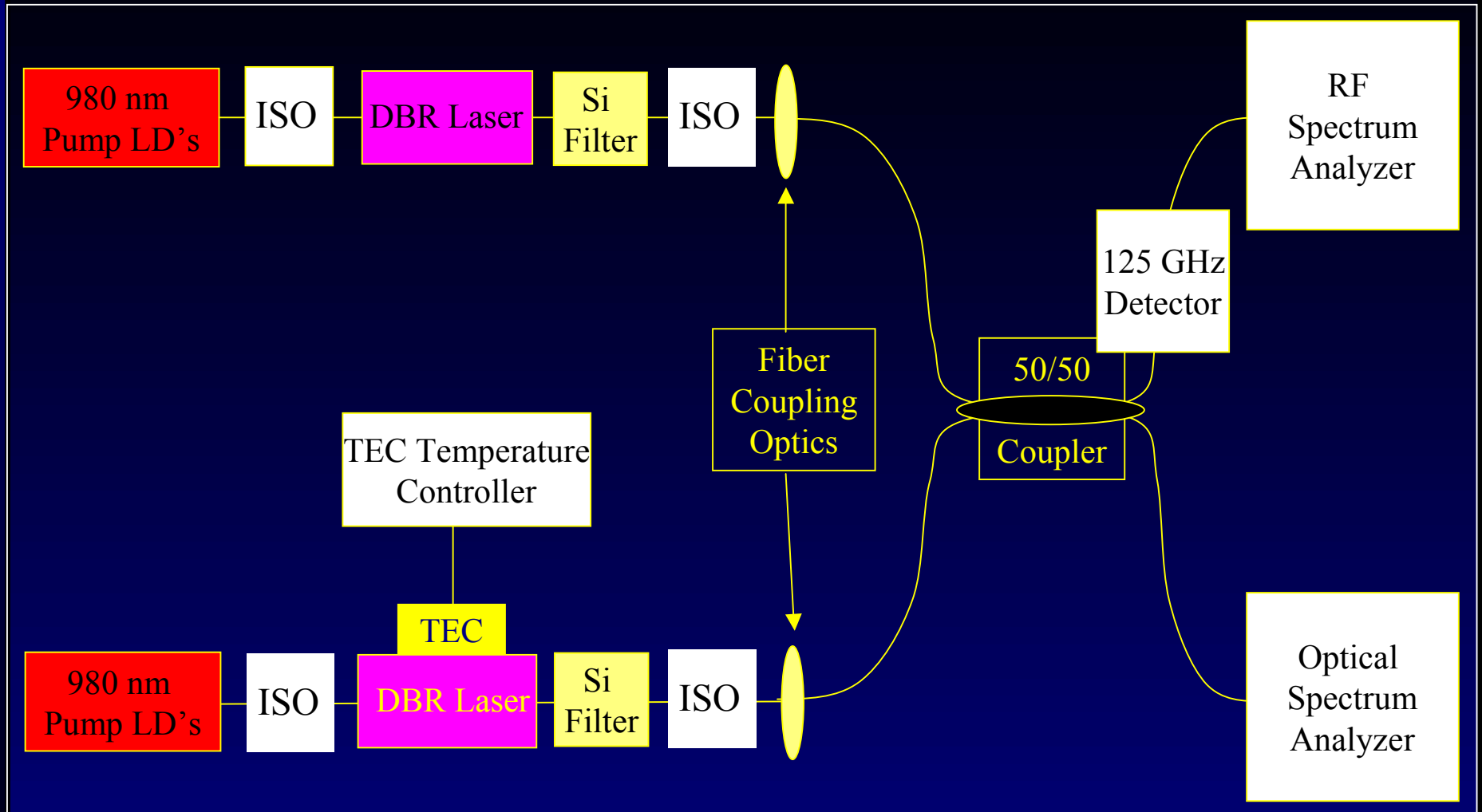
Schawlow-Townes Linewidth Limit



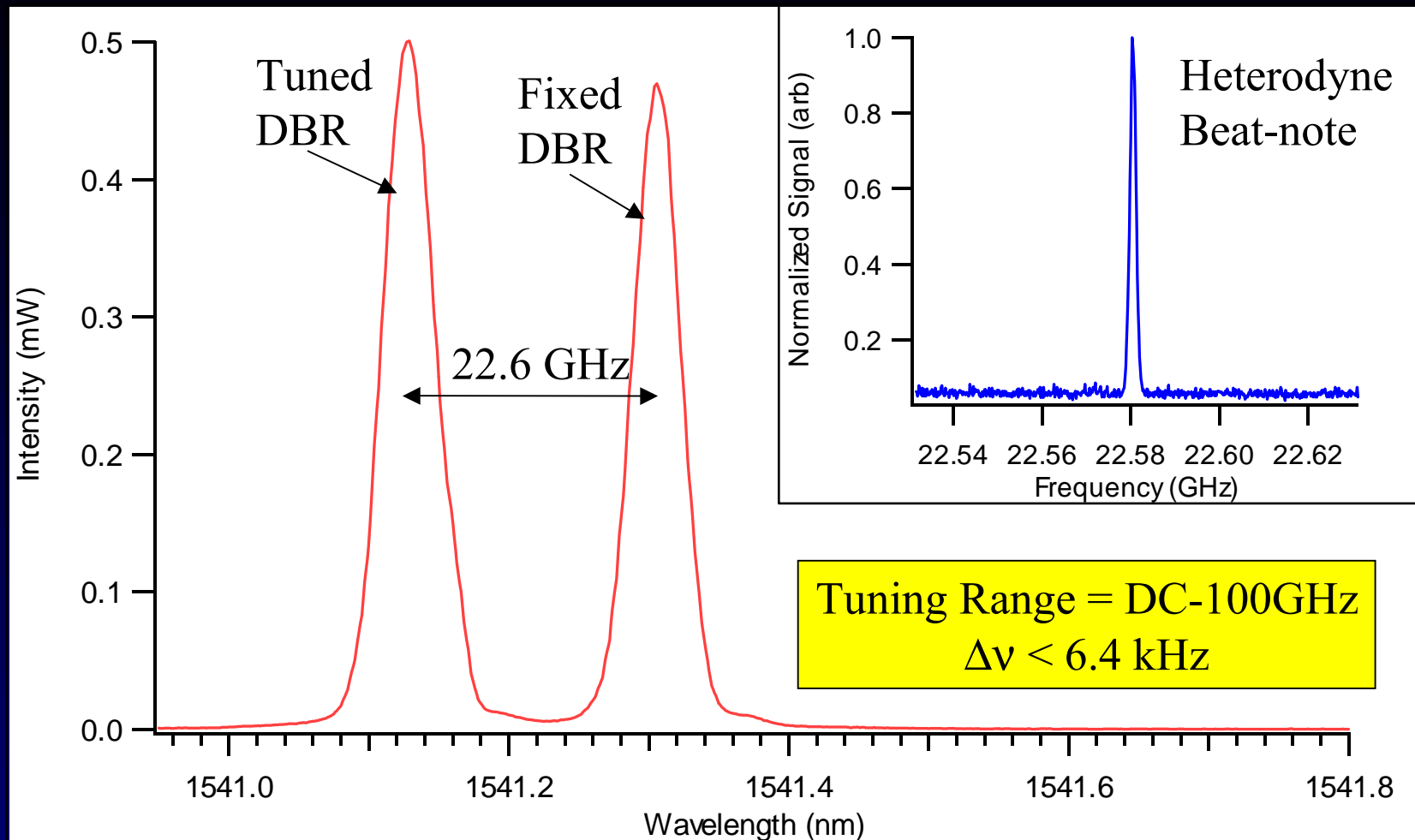
Linewidth Measurement



Optical Heterodyne Set-up

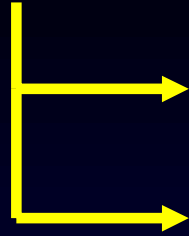


Optical RF & Microwave Frequency Generation



Applications for AOSP

- All optical microwave and RF signal generation.



1 Hz stability with phase
lock to local oscillator.

Phase control.

- Laser sources for photonic crystal oscillators.



High-Q resonators with large dispersion
require narrow linewidth sources.

- Other wavelengths available



980 nm, 1050 nm, 1350 nm

- Compact size

Acknowledgements

-NIST Internal funding